

2SB1101, 2SB1102

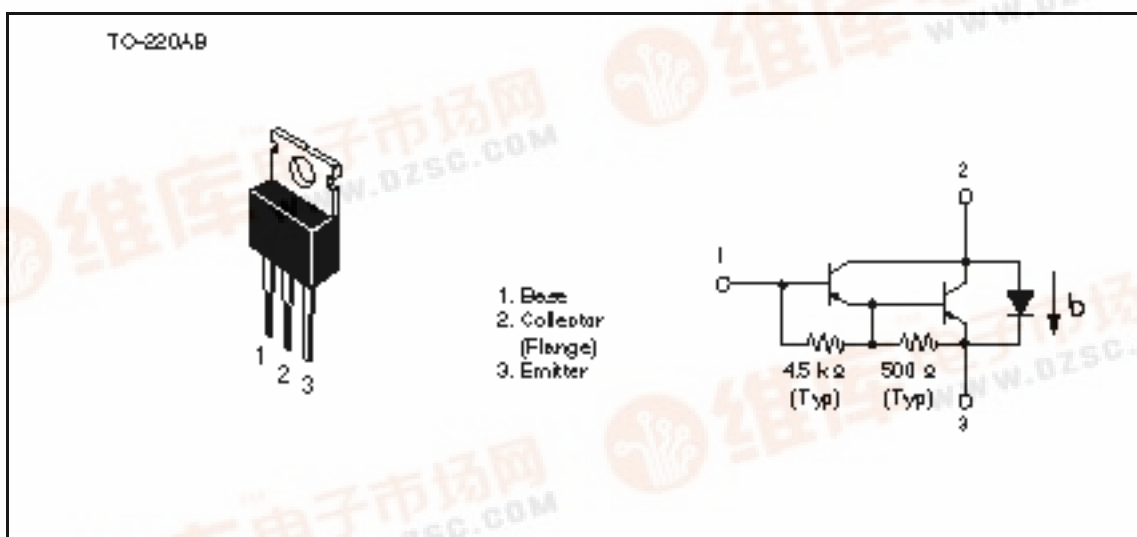
Silicon PNP Triple Diffused

HITACHI

Application

Low frequency power amplifier

Outline



2SB1101, 2SB1102

Absolute Maximum Ratings (Ta = 25°C)

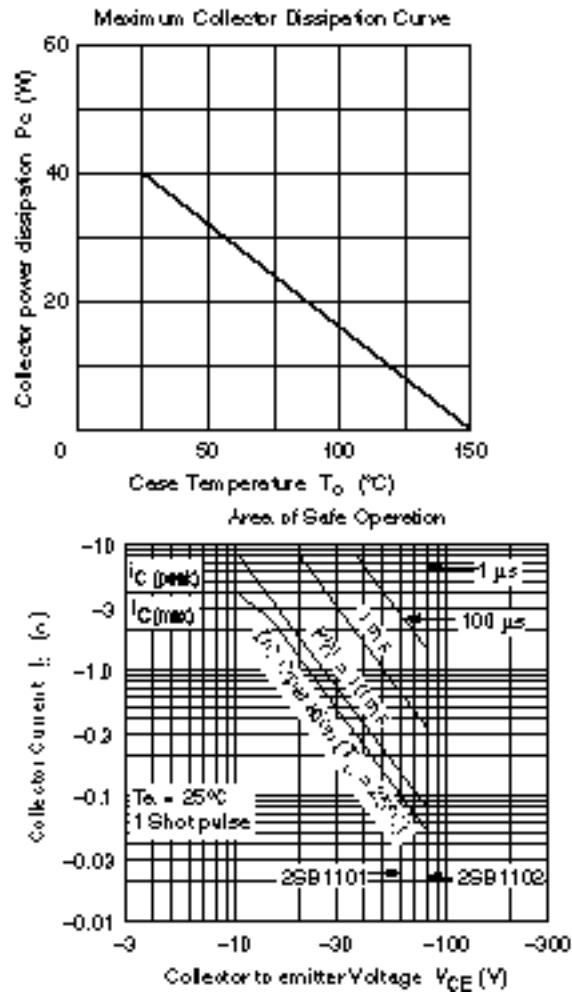
Item	Symbol	Ratings		Unit
		2SB1101	2SB1102	
Collector to base voltage	V_{CBO}	-60	-80	V
Collector to emitter voltage	V_{CEO}	-60	-80	V
Emitter to base voltage	V_{EBO}	-7	-7	V
Collector current	I_C	-4	-4	A
Collector peak current	$I_{C(peak)}$	-8	-8	A
Collector power dissipation	P_C^{*1}	40	40	W
Junction temperature	T_j	150	150	°C
Storage temperature	T_{stg}	-55 to +150	-55 to +150	°C
C to E diode forward current	I_D^{*1}	4	4	A

Note: 1. Value at $T_C = 25^\circ\text{C}$.

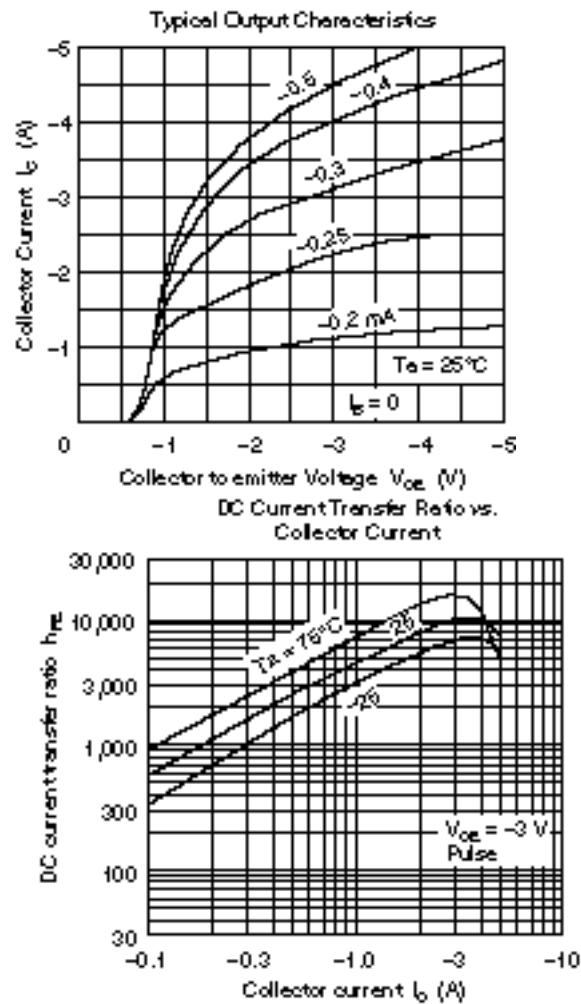
Electrical Characteristics (Ta = 25°C)

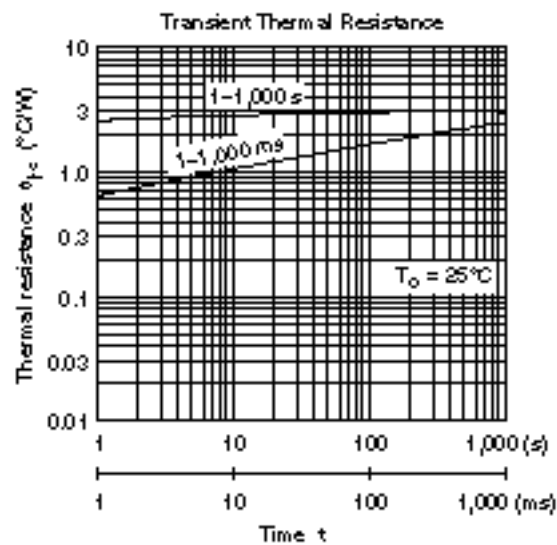
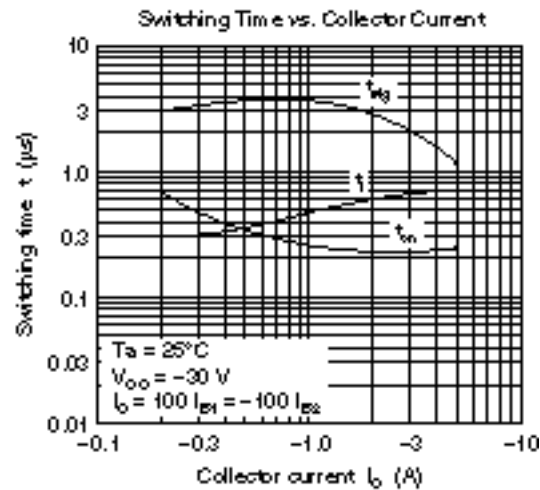
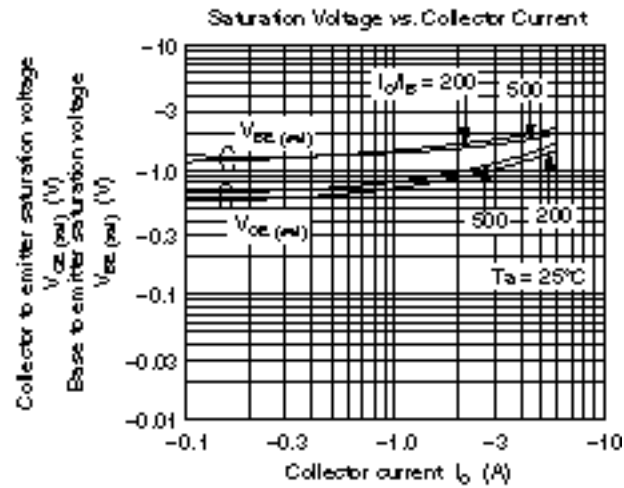
Item	Symbol	2SB1101			2SB1102			Unit	Test conditions
		Min	Typ	Max	Min	Typ	Max		
Collector to emitter breakdown voltage	$V_{(BR)CEO}$	-60	—	—	-80	—	—	V	$I_C = -25\text{ mA}$, $R_{BE} =$
Emitter to base breakdown voltage	$V_{(BR)EBO}$	-7	—	—	-7	—	—	V	$I_E = -50\text{ mA}$, $I_C = 0$
Collector cutoff current	I_{CBO}	—	—	-100	—	—	-100	μA	$V_{CB} = -60\text{ V}$, $I_E = 0$
	I_{CEO}	—	—	-10	—	—	-10	μA	$V_{CE} = -50\text{ V}$, $R_{BE} =$
DC current transfer ratio	h_{FE}	1000	—	20000	1000	—	20000		$V_{CE} = -3\text{ V}$, $I_C = -2\text{ A}^{*1}$
Collector to emitter saturation voltage	$V_{CE(sat)1}$	—	—	-1.5	—	—	-1.5	V	$I_C = -2\text{ A}$, $I_B = -4\text{ mA}^{*1}$
	$V_{CE(sat)2}$	—	—	-3.0	—	—	-3.0		$I_C = -4\text{ A}$, $I_B = -40\text{ mA}^{*1}$
Base to emitter saturation voltage	$V_{BE(sat)1}$	—	—	-2.0	—	—	-2.0	V	$I_C = -2\text{ A}$, $I_B = -4\text{ mA}^{*1}$
	$V_{BE(sat)2}$	—	—	-3.5	—	—	-3.5		$I_C = -4\text{ A}$, $I_B = -40\text{ mA}^{*1}$
C to E diode forward voltage	V_D	—	—	3.0	—	—	3.0	V	$I_D = 4\text{ A}$
Turn on time	t_{on}	—	0.8	—	—	0.8	—	μs	$I_C = -2\text{ A}$,
Storage time	t_{stg}	—	4.0	—	—	4.0	—		$I_{B1} = -I_{B2} = -4\text{ mA}$
Fall time	t_f	—	1.0	—	—	1.0	—		

Note: 1. Pulse Test.



2SB1101, 2SB1102





2SB1101, 2SB1102

When using this document, keep the following in mind:

1. This document may, wholly or partially, be subject to change without notice.
2. All rights are reserved: No one is permitted to reproduce or duplicate, in any form, the whole or part of this document without Hitachi's permission.
3. Hitachi will not be held responsible for any damage to the user that may result from accidents or any other reasons during operation of the user's unit according to this document.
4. Circuitry and other examples described herein are meant merely to indicate the characteristics and performance of Hitachi's semiconductor products. Hitachi assumes no responsibility for any intellectual property claims or other problems that may result from applications based on the examples described herein.
5. No license is granted by implication or otherwise under any patents or other rights of any third party or Hitachi, Ltd.
6. MEDICAL APPLICATIONS: Hitachi's products are not authorized for use in MEDICAL APPLICATIONS without the written consent of the appropriate officer of Hitachi's sales company. Such use includes, but is not limited to, use in life support systems. Buyers of Hitachi's products are requested to notify the relevant Hitachi sales offices when planning to use the products in MEDICAL APPLICATIONS.

HITACHI

Hitachi, Ltd.

Semiconductor & IC Div.

Nippon Bldg., 2-6-2, Ohite-machi, Chiyoda-ku, Tokyo 100, Japan

Tel Tokyo (03) 3270-2111

Fax (03) 3270-5109

For further information write to:

Hitachi America, Ltd.

Semiconductor & IC Div.

2000 Sierra Point Parkway

Brisbane, CA 94005-4835

U.S.A.

Tel 415-589-8300

Fax 415-583-4207

Hitachi Europe GmbH

Electronic Components Group

Continental Europe

Danewer Straße 3

D-85622 Feldkirchen

München

Tel 089-9 94 80-0

Fax 089-9 29 30 00

Hitachi Europe Ltd.

Electronic Components Div.

Northern Europe Headquarters

Whitbrook Park

Lower Cookham Road

M Maidenhead

Berkshire SL6 6YA

United Kingdom

Tel 0628-585000

Fax 0628-778322

Hitachi Asia Pte. Ltd.

45 Collyer Quay #20-00

Hitachi Tower

Singapore 0104

Tel 535-2100

Fax 535-1533

Hitachi Asia (Hong Kong) Ltd.

Unit 705, North Tower,

World Finance Centre

Harbour City, Canton Road

Tsim Sha Tsui, Kowloon

Hong Kong

Tel 27352218

Fax 27308074